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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/467,675	12/21/1999	FU-TAI LIOU	252103-4540	2680
7	590 08/11/2003			
J.C. PATENT			EXAMINER	
SUITE-250			· NADAV, ORI	
IRVINE, CA	92018		ART UNIT	PAPER NUMBER
			2811	
			DATE MAIL ED: 09/11/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		1hv				
	Application N .	Applicant(s)				
Office Action Summan	09/467,675	LIOU ET AL.				
Office Action Summary	Examiner	Art Unit				
	ori nadav	2811				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Peri df r Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status						
1) Responsive to communication(s) filed on 10.	<i>luly</i> 2003 .					
2a)⊠ This action is FINAL . 2b)⊡ Th	is action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims	•	•				
4)⊠ Claim(s) <u>1-16 and 19-21</u> is/are pending in the	application.					
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-16 and 19-21</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement. Application Papers						
9)☐ The specification is objected to by the Examine	г.					
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) All b) Some * c) None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) 🔲 Notice of Inform	nary (PTO-413) Paper No(s) al Patent Application (PTO-152)				
U.S. Patent and Trademark Office PTO-326 (Rev. 04-01) Office Ac	tion Summary	Part of Paper No. 24				

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 1. Claims 1-16 and 19-21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamaguchi et al. (6,118,154) in view of Hu et al. (6,121,077) and Japanese Patent #4-76959.

Yamaguchi et al. teach in figure 22 an ESD protection structure having a silicon sided diode used to protect an internal circuit, the ESD protection structure electrically connected between an input pad 30 and a node 42 and the internal circuit electrically connected to the node (figure 19), comprising an input resistor including a plurality of crystal silicon resistors 36, 37 formed over an insulating oxide material layer 2, electrically coupled between the input pad 30 and the node 42, and horizontally isolated by an isolation structure, at least a single crystal silicon sided P/N junction diode 38 formed over the insulating material layer 2, wherein the diode is electrically coupled between one terminal of a corresponding power supply 32 and a node 42.

Yamaguchi et al. do not teach in the embodiment of figure 22 a silicon layer comprising monocrystalline silicon.

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Hu et al. teach an ESD protection circuit having an SOI structure formed of monocrystalline silicon (column 1, line 27).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use a silicon layer comprising monocrystalline silicon in Yamaguchi et al.'s because it is conventional in the art to form ESD protection device having an SOI structure of monocrystalline silicon in order to improve the performance of the device by the use of a monocrystalline silicon. Furthermore, the advantages of using a single crystal resistor over a polycrystalline resistor are well known in the art. Note Japanese patent # 3-142868 is cited to support the well known position.

Regarding claims 4 and 10, Yamaguchi et al. teach an input buffer 37 electrically coupled between the node and the internal circuit.

Regarding claims 7 and 13, Yamaguchi et al. teach a diode comprising a MOS transistor formed over the insulating layer, wherein one of the source/drain regions electrically connects to a gate by a wire line.

Regarding claim 8, Yamaguchi et al. teach junction diodes comprising first and second diodes, electrically connected between the node and one terminal of a first and second power supply, respectively.

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Regarding claim 14, Yamaguchi et al. teach in figure 22 first, second and third conductive layers 13, 14, 15 formed over the insulating layer and electrically connecting the resistor between the input and the integrated circuit and the diode to the integrated circuit, respectively.

Regarding claim 19, Yamaguchi et al. (figures 10 and 22, #11) and Hu et al. (figure 14) teach resistors isolated by an isolation structure.

Regarding claim 20, it is conventional to use STI as an isolation structure, of which judicial notice is taken.

Response to Arguments

Applicant's arguments with respect to claims 1-16 and 18-21 have
 been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used only for papers related to Group 2811 applications.

Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to *Examiner Nadav* whose telephone number is

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(703) 308-8138. The Examiner is in the Office generally between the hours of 7

AM to 4 PM (Eastern Standard Time) Monday through Friday.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center Receptionists** whose telephone number is **308-0956**

O.N. August 8, 2003 ORI NADAV
PATENT EXAMINER
TECHNOLOGY CENTER 2800

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